

September 1983 Revised January 2005

# MM74HCU04 **Hex Inverter**

## **General Description**

The MM74HCU04 inverters utilize advanced silicon-gate CMOS technology to achieve operating speeds similar to LS-TTL gates with the low power consumption of standard CMOS integrated circuits.

The MM74HCU04 is an unbuffered inverter. It has high noise immunity and the ability to drive 15 LS-TTL loads. The 74HCU logic family is functionally as well as pin-out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to  $V_{\mbox{\footnotesize CC}}$  and ground.

#### **Features**

- Typical propagation delay: 7 ns
- Fanout of 15 LS-TTL loads
- Quiescent power consumption: 10 µA maximum at room temperature
- Low input current: 1 µA maximum

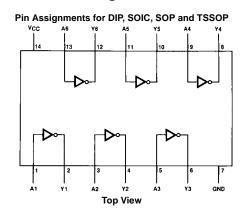
### **Ordering Code:**

Order Number	Package Number	Package Description
MM74HCU04M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HCU04MX_NL	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HCU04SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HCU04MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HCU04N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
MM74HCU04N_NL	N14A	Pb-Free 14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

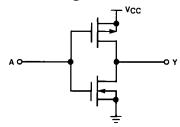
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Pb-Free package per JEDEC J-STD-020B.

#### **Connection Diagram**



# **Schematic Diagram**



# Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V<sub>CC</sub>) -0.5 to +7.0V DC Input Voltage (V<sub>IN</sub>) -1.5 to  $V_{CC} + 1.5V$ DC Output Voltage (V<sub>OUT</sub>) -0.5 to  $V_{CC}$  +0.5VClamp Diode Current (I<sub>IK</sub>, I<sub>OK</sub>) ±20 mA DC Output Current, per pin (I<sub>OUT</sub>) ±25 mA DC  $V_{CC}$  or GND Current, per pin ( $I_{CC}$ ) ±50 mA Storage Temperature Range (T<sub>STG</sub>) –65°C to +150°C Power Dissipation (P<sub>D</sub>) (Note 3) 600 mW

S.O. Package only 500 mW

Lead Temperature (T<sub>L</sub>)

(Soldering 10 seconds) 260°C

### **Recommended Operating Conditions**

	Min	Max	Units
Supply Voltage (V <sub>CC</sub> )	2	6	V
DC Input or Output Voltage	0	$V_{CC}$	V
$(V_{IN}, V_{OUT})$			
Operating Temperature Range (T <sub>A</sub> )	-40	+85	°C

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground. Note 3: Power Dissipation temperature derating — plastic "N" package: -

12 mW/°C from 65°C to 85°C.

#### DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	v <sub>cc</sub>	T <sub>A</sub> = 25°C		$T_A = -40 \text{ to } 85^{\circ}\text{C}$ $T_A = -55 \text{ to } 125^{\circ}\text{C}$		Units
Symbol			VCC	Тур		Guaranteed L	imits	Units
V <sub>IH</sub>	Minimum HIGH Level		2.0V		1.7	1.7	1.7	V
	Input Voltage		4.5V		3.6	3.6	3.6	V
			6.0V		4.8	4.8	4.8	V
V <sub>IL</sub>	Maximum LOW Level		2.0V		0.3	0.3	0.3	V
	Input Voltage		4.5V		0.8	0.8	0.8	V
			6.0V		1.1	1.1	1.1	V
V <sub>OH</sub>	Minimum HIGH Level	$V_{IN} = V_{IL}$						
	Output Voltage	$ I_{OUT}  \le 20 \mu A$	2.0V	2.0	1.8	1.8	1.8	V
			4.5V	4.5	4.0	4.0	4.0	V
			6.0V	6.0	5.5	5.5	5.5	V
		V <sub>IN</sub> = GND	1			1		
		$ I_{OUT}  \le 4.0 \text{ mA}$	4.5V	4.2	3.98	3.84	3.7	V
		$ I_{OUT}  \le 5.2 \text{ mA}$	6.0V	5.7	5.48	5.34	5.2	V
V <sub>OL</sub>	Maximum LOW Level	$V_{IN} = V_{IH}$						
	Output Voltage	$ I_{OUT}  \le 20 \ \mu A$	2.0V	0	0.2	0.2	0.2	V
			4.5V	0	0.5	0.5	0.5	V
			6.0V	0	0.5	0.5	0.5	V
		$V_{IN} = V_{CC}$						
		$ I_{OUT}  \le 6.0 \text{ mA}$	4.5V	0.2	0.26	0.33	0.4	V
		$ I_{OUT}  \le 7.8 \text{ mA}$	6.0V	0.2	0.26	0.33	0.4	V
I <sub>IN</sub>	Maximum Input	$V_{IN} = V_{CC}$ or GND	6.0V		±0.1	±1.0	±1.0	μΑ
	Current							
I <sub>CC</sub>	Maximum Quiescent	$V_{IN} = V_{CC}$ or GND	6.0V		2.0	20	40	μΑ
	Supply Current	$I_{OUT} = 0 \mu A$						

Note 4: For a power supply of 5V ±10% the worst case output voltages (V<sub>OH</sub>, and V<sub>OL</sub>) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case  $V_{IH}$  and  $V_{IL}$  occur at  $V_{CC} = 5.5V$  and 4.5V respectively. (The  $V_{IH}$  value at 5.5V is 3.85V.) The worst case leakage curvature of the  $V_{IH}$  value at  $V_{IH}$  value rent (I<sub>IN</sub>, I<sub>CC</sub>, and I<sub>OZ</sub>) occur for CMOS at the higher voltage and so the 6.0V values should be used.

### **AC Electrical Characteristics**

 $V_{CC} = 5V$ ,  $T_A = 25^{\circ}C$ ,  $C_L = 15$  pF,  $t_r = t_f = 6$  ns

Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation		7	13	ns
	Delay				

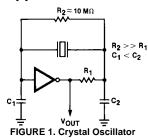
#### **AC Electrical Characteristics**

 $V_{CC} = 2.0 V$  to 6.0V,  $C_L = 50$  pF,  $t_f = t_f = 6$  ns (unless otherwise specified)

Symbol	Parameter	Conditions	v <sub>cc</sub>	T <sub>A</sub> =25°C		T <sub>A</sub> =-40 to 85°C	T <sub>A</sub> =-55 to 125°C	Units
				Typ Guaranteed Limits				Onits
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation		2.0V	49	82	103	120	ns
	Delay		4.5V	9.9	16	21	24	ns
			6.0V	8.4	14	18	20	ns
t <sub>TLH</sub> , t <sub>THL</sub>	Maximum Output Rise		2.0V	30	75	95	110	ns
	and Fall Time		4.5V	8	15	19	22	ns
			6.0V	7	13	16	19	ns
C <sub>PD</sub>	Power Dissipation	(per gate)		90				pF
	Capacitance (Note 5)							
C <sub>IN</sub>	Maximum Input			8	15	15	15	pF
	Capacitance							

Note 5:  $C_{PD}$  determines the no load dynamic power consumption,  $P_D = C_{PD} \ V_{CC}^2 \ f + I_{CC} \ V_{CC}$ , and the no load dynamic current consumption,  $I_S = C_{PD} \ V_{CC} \ f + I_{CC}$ .

# **Typical Applications**



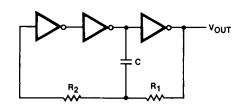
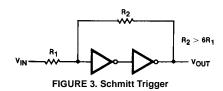
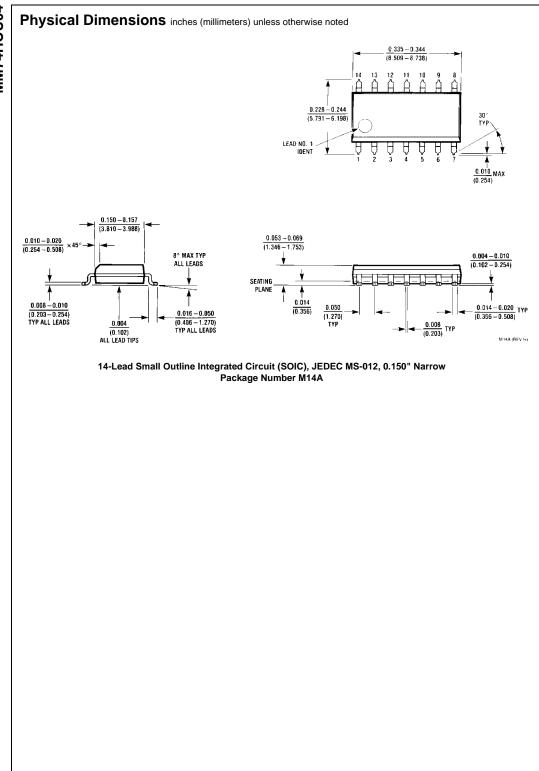
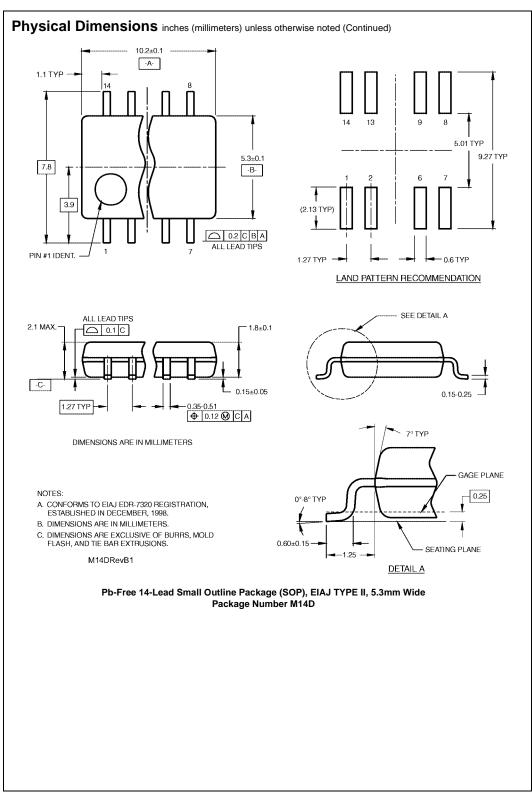
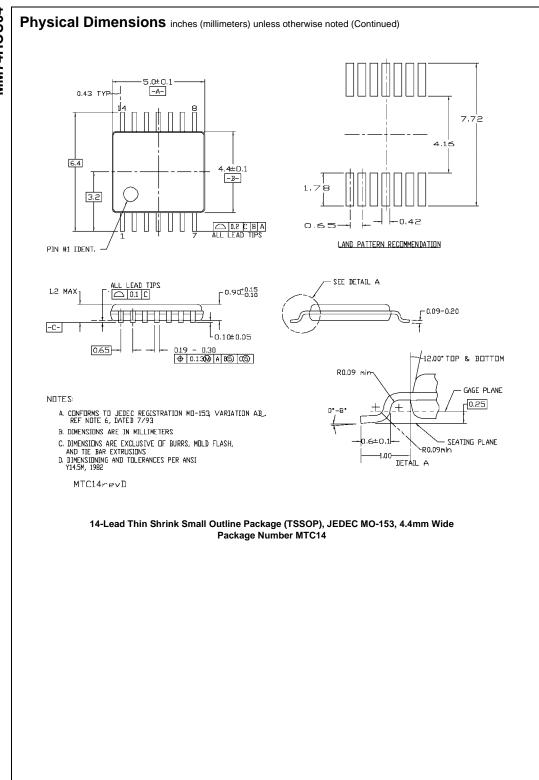


FIGURE 2. Stable RC Oscillator









#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued) 0.740 - 0.770(18.80 - 19.56)0.090 (2.286) 14 13 12 14 13 12 11 10 9 8 0.250 ± 0.010 PIN NO. 1 IDENT PIN NO. 1 IDENT 1 2 3 4 5 6 7 1 2 3 $\frac{0.092}{(2.337)}$ DIA $\frac{0.030}{(0.762)}$ MAX OPTION 1 OPTION 02 $\frac{0.135 \pm 0.005}{(3.429 \pm 0.127)}$ 0.300 - 0.320 $\overline{(7.620 - 8.128)}$ 0.065 $\frac{0.145 - 0.200}{(3.683 - 5.080)}$ 0.060 4° TYP Optional (1.524) (1.651) $\frac{0.008 - 0.016}{(0.203 - 0.406)}$ TYP 0.020 (0.508) 0.125 - 0.150 $0.075 \pm 0.015$ (3.175 - 3.810)0.280 (1.905 ± 0.381) (7.112) MIN 0.014 - 0.0230.100 ± 0.010 (2.540 ± 0.254) TYP (0.356 - 0.584) $\frac{0.050 \pm 0.010}{(1.270 - 0.254)}$ TYP 0.325 <sup>+0.040</sup> -0.015

14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

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 $8.255 + 1.016 \\ -0.381$ 

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N144 (REV.E)